NSN 5962-01-234-5150

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View Online at https://aerobasegroup.com/nsn/5962-01-234-5150 **Body Length:** 1.060 inches **Body Width:** 0.350 inches **Body Height:** 0.205 inches **Maximum Power Dissipation Rating:** 853.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 5820-01-172-2886 symbol generato **Features Provided:** Hermetically sealed and burn in and monolithic and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 7.0 volts power source **Time Rating Per Chacteristic:** 40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

N/a

Terminal Type And Quantity:

20 printed circuit Shelf Life:

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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